

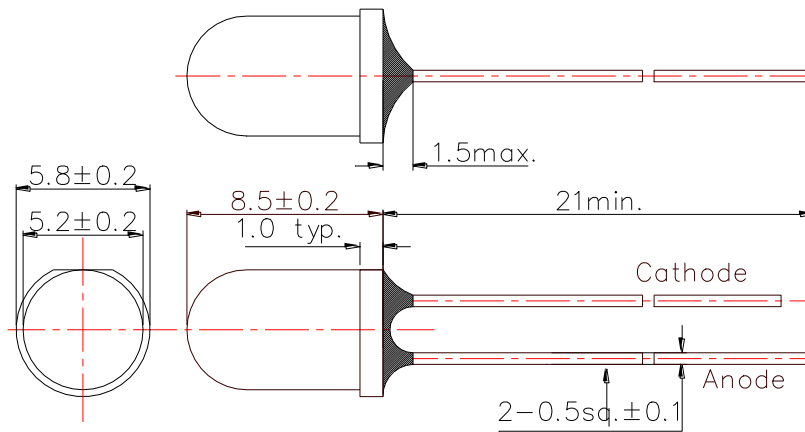
Data Sheet

L910D-02

Infrared LED Lamp

USHIO

Outline and Internal Circuit



(Unit : mm)

Features

- Chip Material : AlGaAs
- Chip Dimension : 350um * 350um
- Number of Chips : 1pce
- Peak Wavelength : 910nm typ.
- Package Type : $\phi 5$ mm clear molding
- Lead Frame : Soldered (Lead Free)
- Lens : Epoxy Resin

Application

Absolute Maximum Ratings (Tc=25°C)

| Item | Symbol | Ratings | Unit |
|-----------------------|--------|------------|------|
| Power Dissipation | PD | 200 | mW |
| Forward Current | IF | 100 | mA |
| Pulse Forward Current | IFP | 1000 | mA |
| Reverse Voltage | VR | 5 | V |
| Thermal Resistance | Rthja | 250 | K/W |
| Junction Temperature | Tj | 120 | °C |
| Operating Temperature | Topr | -40 ~ +100 | °C |
| Storage Temperature | Tstg | -40 ~ +100 | °C |
| Soldering Temperature | TSOL | 265 | °C |

‡Pulse Forward Current condition : Duty 1% and Pulse Width=10us.

‡Soldering condition : Soldering condition must be completed with 3 seconds at 265°C

Optical and Electrical Characteristics (Tc=25°C)

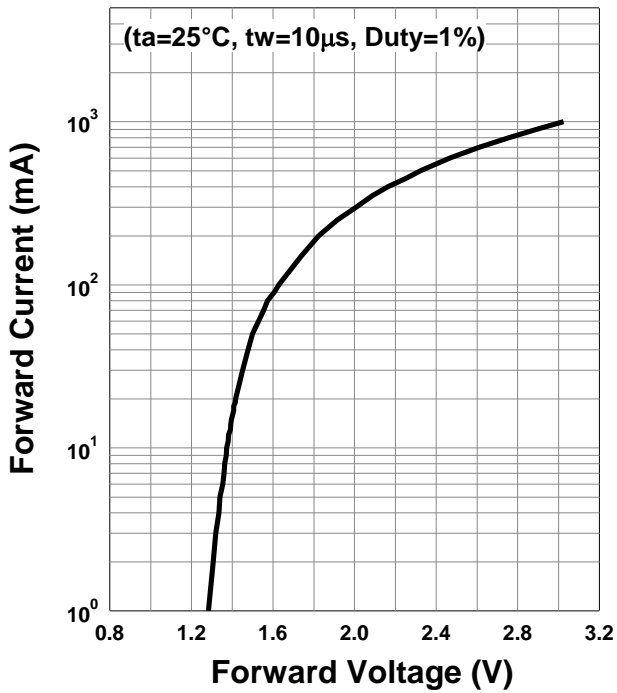
| Parameter | Symbol | Min | Typ | Max | Unit | Test Condition |
|----------------------|-----------------|-----|---------|-------|-------|----------------|
| Forward Voltage | VF | | 1.5 | (2.0) | V | IF=50mA |
| | VFP | | 3.0 | | | IFP=1A |
| Total Radiated Power | PO | | 13 | | mW | IF=50mA |
| | | | 210 | | | IFP=1A |
| Radiant Intensity | IE | | 140 | | mW/sr | IF=50mA |
| | | | 2200 | | | IFP=1A |
| Peak Wavelength | λ_p | 900 | | 920 | nm | IF=50mA |
| Half Width | $\Delta\lambda$ | | 35 | | nm | IF=50mA |
| Viewing Half Angle | $\theta_{1/2}$ | | ± 3 | | deg. | IF=50mA |
| Rise Time | tr | | 50 | | ns | IF=50mA |
| Fall Time | tf | | 50 | | ns | IF=50mA |

‡ Radiated Power is measured by S3584-08.

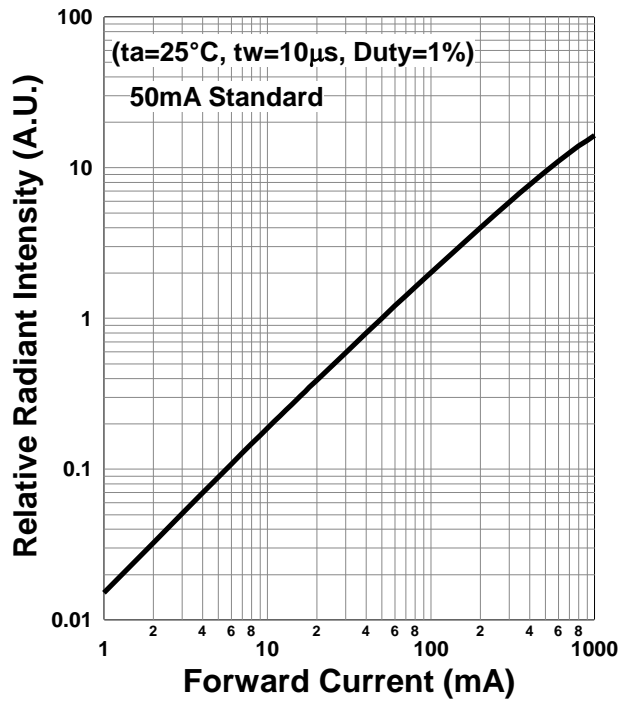
‡ Radiant Intensity is measured by CIE127-2007 Condition B.

Typical Characteristic Curves

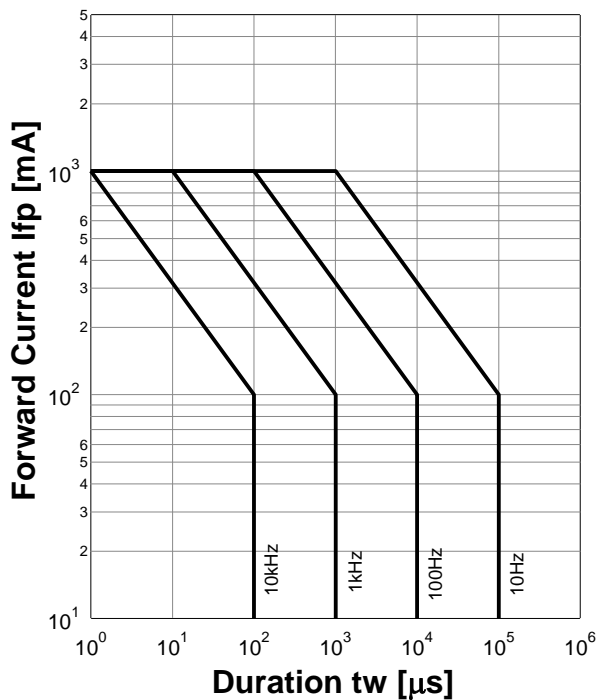
Forward Current - Forward Voltage



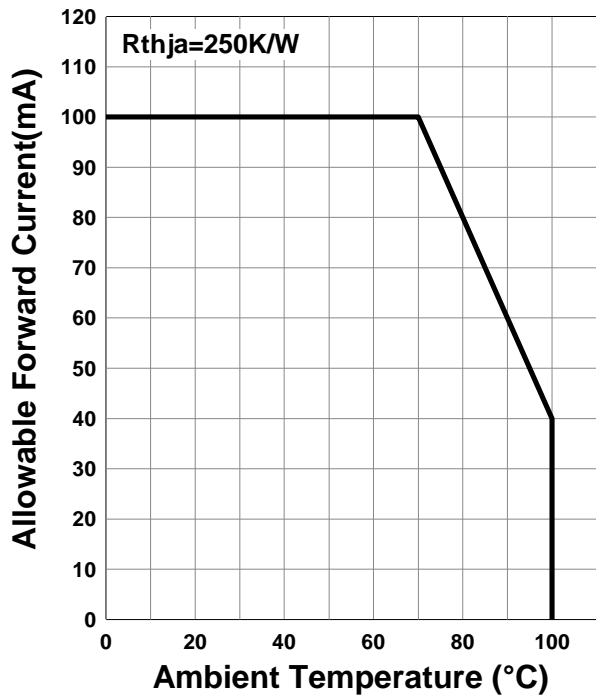
Relative Radiant Intensity - Forward Current



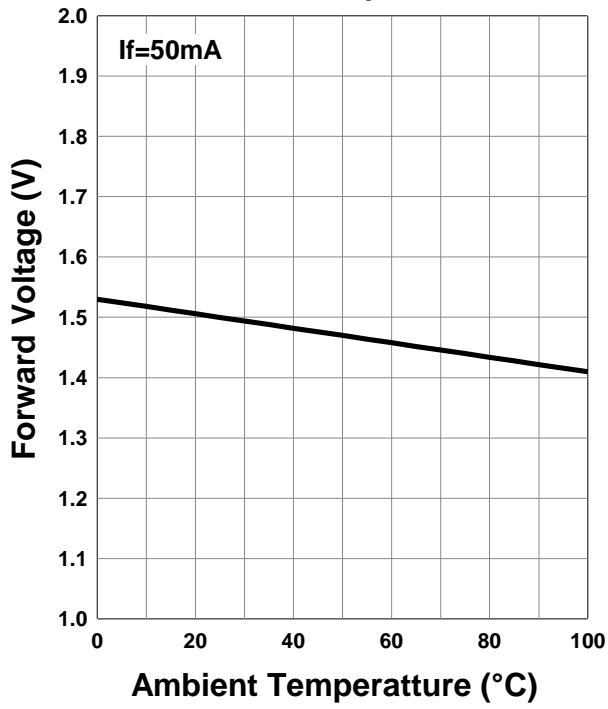
Forward Current - Pulse Duration



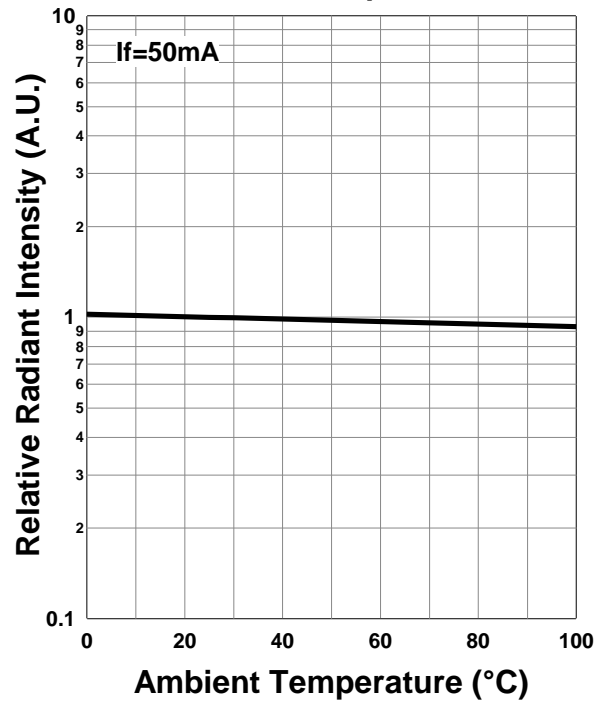
Allowable Forward Current - Ambient Temperature



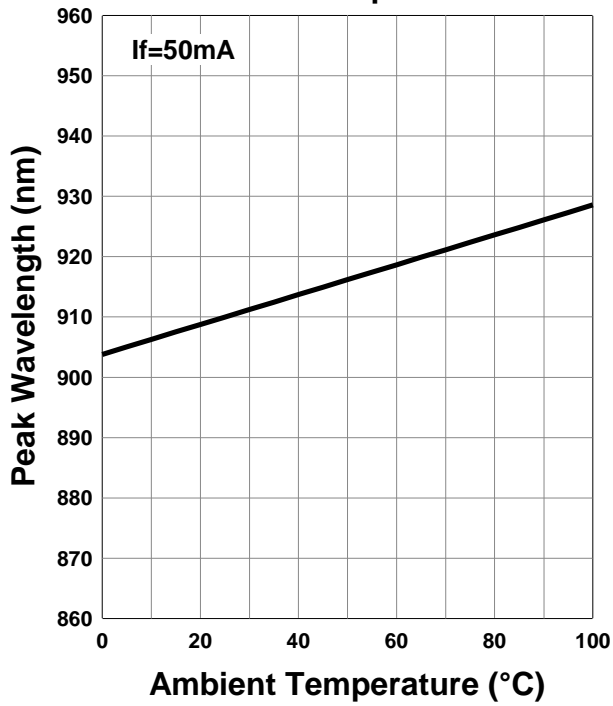
Forward Voltage - Ambient Temperature



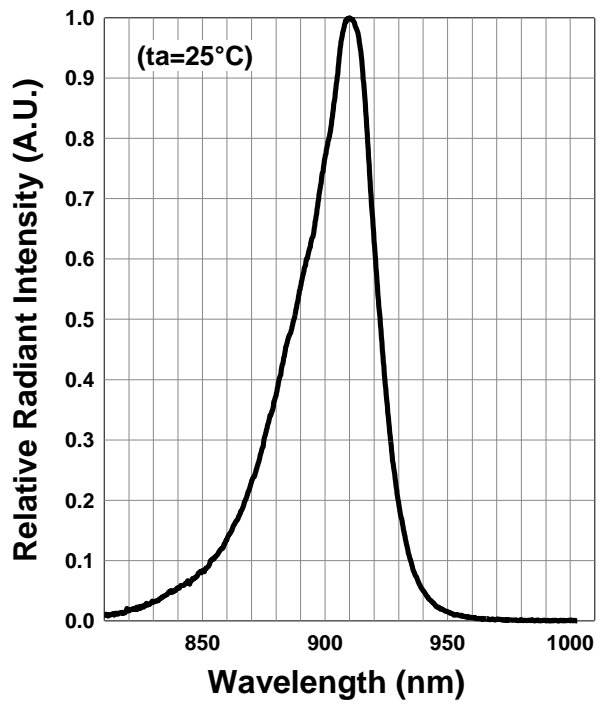
Relative Radiant Intensity - Ambient Temperature



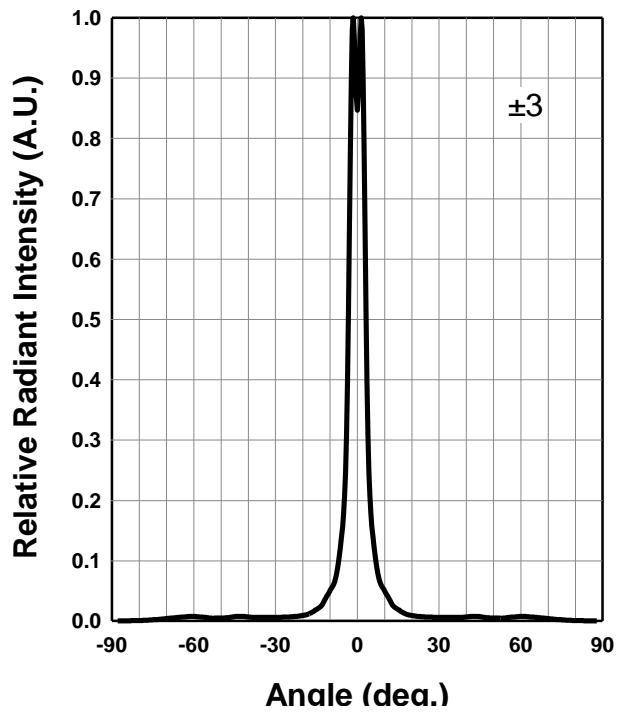
Peak Wavelength - Ambient Temperature



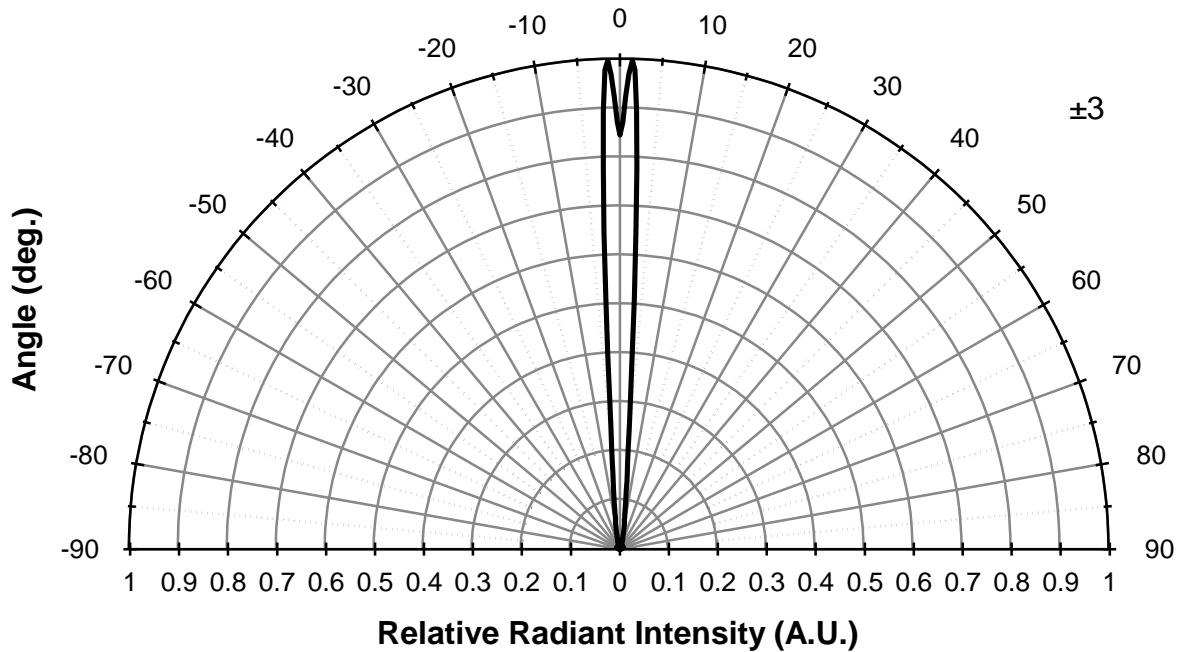
Relative Spectral Emission



Radiation Characteristics



Radiation Characteristics



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Product data and parameters in this catalog are typical values based on reasonably up-to-date measurements.

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